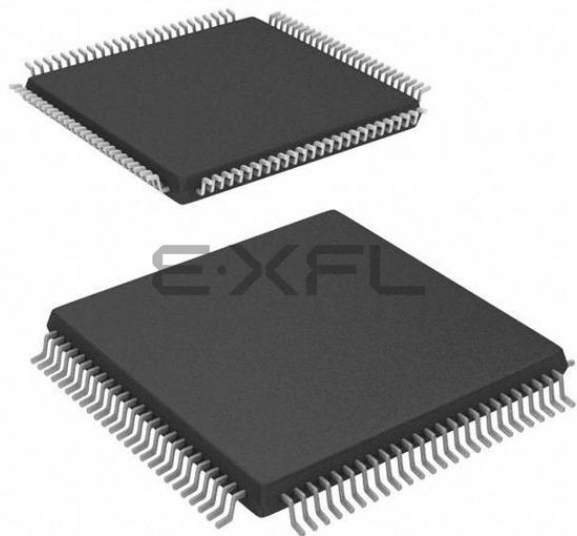




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Understanding [Embedded - FPGAs \(Field Programmable Gate Array\)](#)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

Product Status	Obsolete
Number of LABs/CLBs	196
Number of Logic Elements/Cells	466
Total RAM Bits	6272
Number of I/O	77
Number of Gates	10000
Voltage - Supply	3V ~ 3.6V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	100-TQFP
Supplier Device Package	100-VQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/xilinx/xcs10xl-5vq100c

Output Multiplexer/2-Input Function Generator (Spartan-XL Family Only)

The output path in the Spartan-XL family IOB contains an additional multiplexer not available in the Spartan family IOB. The multiplexer can also be configured as a 2-input function generator, implementing a pass gate, AND gate, OR gate, or XOR gate, with 0, 1, or 2 inverted inputs.

When configured as a multiplexer, this feature allows two output signals to time-share the same output pad, effectively doubling the number of device outputs without requiring a larger, more expensive package. The select input is the pin used for the output flip-flop clock, OK.

When the multiplexer is configured as a 2-input function generator, logic can be implemented within the IOB itself. Combined with a Global buffer, this arrangement allows very high-speed gating of a single signal. For example, a wide decoder can be implemented in CLBs, and its output gated with a Read or Write Strobe driven by a global buffer.

The user can specify that the IOB function generator be used by placing special library symbols beginning with the letter "O." For example, a 2-input AND gate in the IOB function generator is called OAND2. Use the symbol input pin labeled "F" for the signal on the critical path. This signal is placed on the OK pin — the IOB input with the shortest delay to the function generator. Two examples are shown in Figure 7.



Figure 7: AND and MUX Symbols in Spartan-XL IOB

Output Buffer

An active High 3-state signal can be used to place the output buffer in a high-impedance state, implementing 3-state outputs or bidirectional I/O. Under configuration control, the output (O) and output 3-state (T) signals can be inverted. The polarity of these signals is independently configured for each IOB (see Figure 6, page 7). An output can be configured as open-drain (open-collector) by tying the 3-state pin (T) to the output signal, and the input pin (I) to Ground.

By default, a 5V Spartan device output buffer pull-up structure is configured as a TTL-like totem-pole. The High driver is an n-channel pull-up transistor, pulling to a voltage one transistor threshold below V_{CC} . Alternatively, the outputs can be globally configured as CMOS drivers, with additional p-channel pull-up transistors pulling to V_{CC} . This option, applied using the bitstream generation software, applies to all outputs on the device. It is not individually programmable.

All Spartan-XL device outputs are configured as CMOS drivers, therefore driving rail-to-rail. The Spartan-XL family outputs are individually programmable for 12 mA or 24 mA output drive.

Any 5V Spartan device with its outputs configured in TTL mode can drive the inputs of any typical 3.3V device. Supported destinations for Spartan/XL device outputs are shown in Table 7.

Three-State Register (Spartan-XL Family Only)

Spartan-XL devices incorporate an optional register controlling the three-state enable in the IOBs. The use of the three-state control register can significantly improve output enable and disable time.

Output Slew Rate

The slew rate of each output buffer is, by default, reduced, to minimize power bus transients when switching non-critical signals. For critical signals, attach a FAST attribute or property to the output buffer or flip-flop.

Spartan/XL devices have a feature called "Soft Start-up," designed to reduce ground bounce when all outputs are turned on simultaneously at the end of configuration. When the configuration process is finished and the device starts up, the first activation of the outputs is automatically slew-rate limited. Immediately following the initial activation of the I/O, the slew rate of the individual outputs is determined by the individual configuration option for each IOB.

Pull-up and Pull-down Network

Programmable pull-up and pull-down resistors are used for tying unused pins to V_{CC} or Ground to minimize power consumption and reduce noise sensitivity. The configurable pull-up resistor is a p-channel transistor that pulls to V_{CC} . The configurable pull-down resistor is an n-channel transistor that pulls to Ground. The value of these resistors is typically 20 K Ω – 100 K Ω (See "Spartan Family DC Characteristics Over Operating Conditions" on page 43.).

- The 16 x 1 single-port configuration contains a RAM array with 16 locations, each one-bit wide. One 4-bit address decoder determines the RAM location for write and read operations. There is one input for writing data and one output for reading data, all at the selected address.
- The (16 x 1) x 2 single-port configuration combines two 16 x 1 single-port configurations (each according to the preceding description). There is one data input, one data output and one address decoder for each array. These arrays can be addressed independently.
- The 32 x 1 single-port configuration contains a RAM array with 32 locations, each one-bit wide. There is one data input, one data output, and one 5-bit address decoder.
- The dual-port mode 16 x 1 configuration contains a RAM array with 16 locations, each one-bit wide. There are two 4-bit address decoders, one for each port. One port consists of an input for writing and an output for reading, all at a selected address. The other port consists of one output for reading from an independently selected address.

The appropriate choice of RAM configuration mode for a given design should be based on timing and resource requirements, desired functionality, and the simplicity of the design process. Selection criteria include the following: Whereas the 32 x 1 single-port, the (16 x 1) x 2 single-port, and the 16 x 1 dual-port configurations each use one entire CLB, the 16 x 1 single-port configuration uses only one half of a CLB. Due to its simultaneous read/write capability, the dual-port RAM can transfer twice as much data as the single-port RAM, which permits only one data operation at any given time.

CLB memory configuration options are selected by using the appropriate library symbol in the design entry.

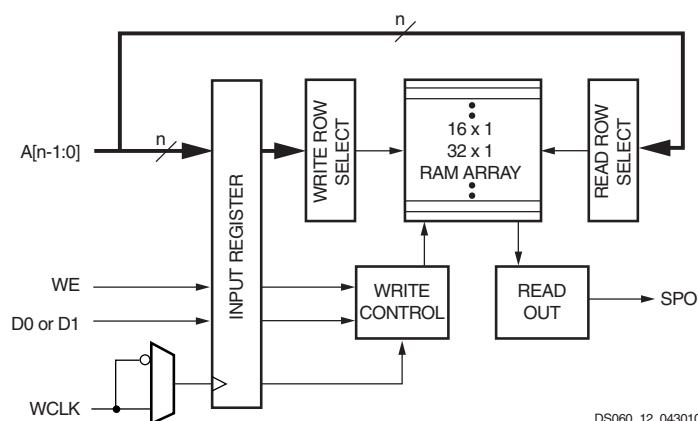
Single-Port Mode

There are three CLB memory configurations for the single-port RAM: 16 x 1, (16 x 1) x 2, and 32 x 1, the functional organization of which is shown in [Figure 12](#).

The single-port RAM signals and the CLB signals ([Figure 2](#), [page 4](#)) from which they are originally derived are shown in [Table 9](#).

Table 9: Single-Port RAM Signals

RAM Signal	Function	CLB Signal
D0 or D1	Data In	DIN or H1
A[3:0]	Address	F[4:1] or G[4:1]
A4 (32 x 1 only)	Address	H1
WE	Write Enable	SR
WCLK	Clock	K
SPO	Single Port Out (Data Out)	F _{OUT} or G _{OUT}



DS060_12_043010

Notes:

1. The (16 x 1) x 2 configuration combines two 16 x 1 single-port RAMs, each with its own independent address bus and data input. The same WE and WCLK signals are connected to both RAMs.
2. $n = 4$ for the 16 x 1 and (16 x 1) x 2 configurations. $n = 5$ for the 32 x 1 configuration.

Figure 12: Logic Diagram for the Single-Port RAM

Writing data to the single-port RAM is essentially the same as writing to a data register. It is an edge-triggered (synchronous) operation performed by applying an address to the A inputs and data to the D input during the active edge of WCLK while WE is High.

The timing relationships are shown in [Figure 13](#). The High logic level on WE enables the input data register for writing. The active edge of WCLK latches the address, input data, and WE signals. Then, an internal write pulse is generated that loads the data into the memory cell.

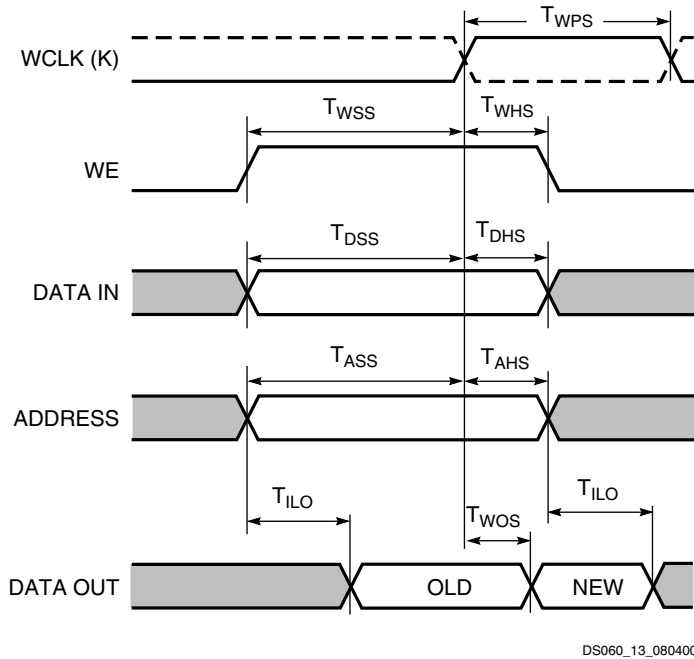


Figure 13: Data Write and Access Timing for RAM

WCLK can be configured as active on either the rising edge (default) or the falling edge. While the WCLK input to the RAM accepts the same signal as the clock input to the associated CLB's flip-flops, the sense of this WCLK input can be

inverted with respect to the sense of the flip-flop clock inputs. Consequently, within the same CLB, data at the RAM SPO line can be stored in a flip-flop with either the same or the inverse clock polarity used to write data to the RAM.

The WE input is active High and cannot be inverted within the CLB.

Allowing for settling time, the data on the SPO output reflects the contents of the RAM location currently addressed. When the address changes, following the asynchronous delay T_{ILO} , the data stored at the new address location will appear on SPO. If the data at a particular RAM address is overwritten, after the delay T_{WOS} , the new data will appear on SPO.

Dual-Port Mode

In dual-port mode, the function generators (F-LUT and G-LUT) are used to create a 16 x 1 dual-port memory. Of the two data ports available, one permits read and write operations at the address specified by $A[3:0]$ while the second provides only for read operations at the address specified independently by $DPRA[3:0]$. As a result, simultaneous read/write operations at different addresses (or even at the same address) are supported.

The functional organization of the 16 x 1 dual-port RAM is shown in Figure 14. The dual-port RAM signals and the

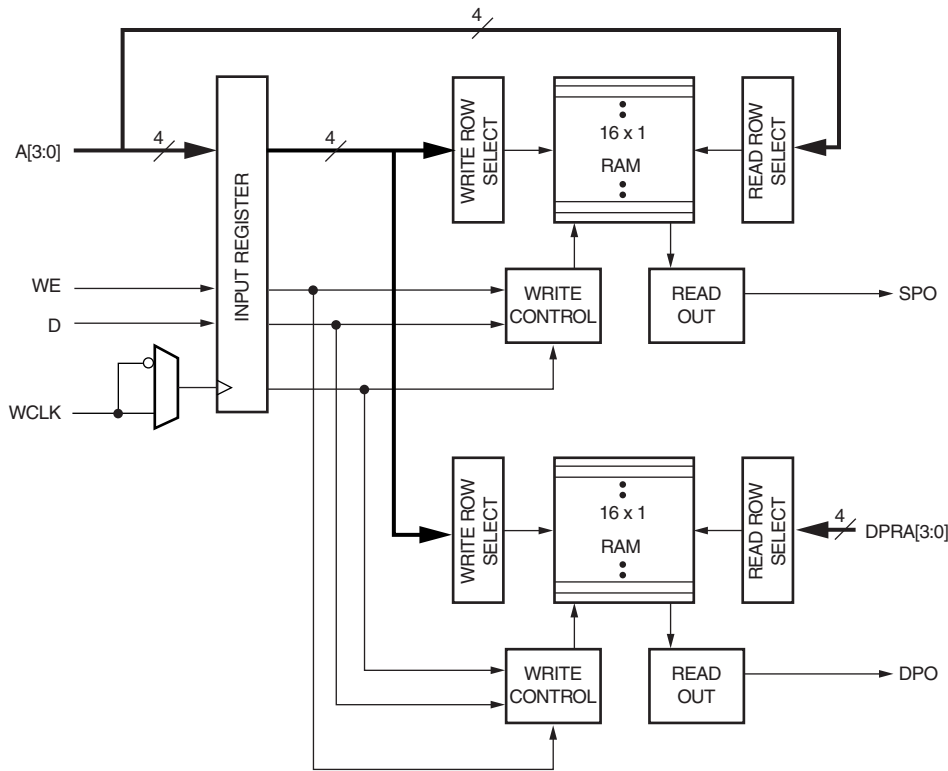
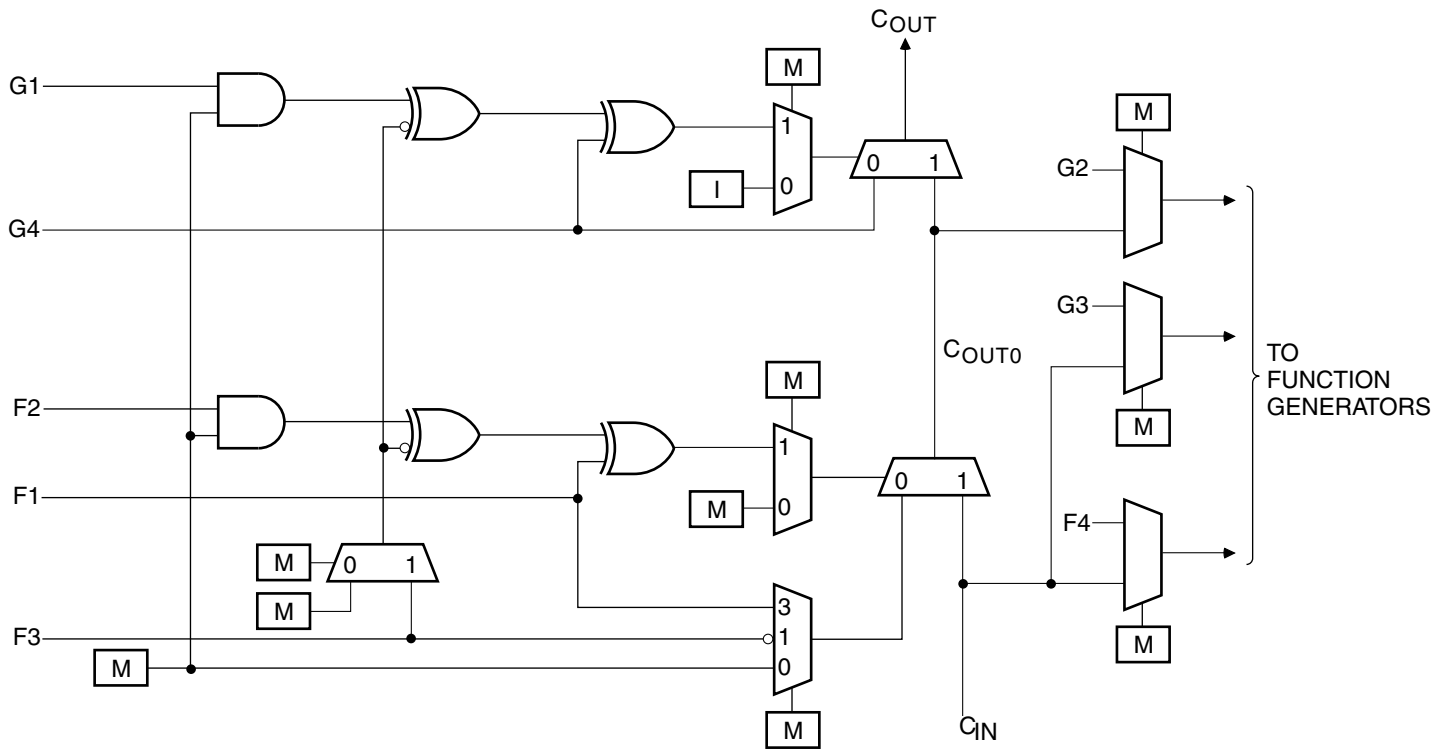


Figure 14: Logic Diagram for the Dual-Port RAM



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Figure 17: Detail of Spartan/XL Dedicated Carry Logic

3-State Long Line Drivers

A pair of 3-state buffers is associated with each CLB in the array. These 3-state buffers (BUFT) can be used to drive signals onto the nearest horizontal longlines above and below the CLB. They can therefore be used to implement multiplexed or bidirectional buses on the horizontal longlines, saving logic resources.

There is a weak keeper at each end of these two horizontal longlines. This circuit prevents undefined floating levels. However, it is overridden by any driver.

The buffer enable is an active High 3-state (i.e., an active Low enable), as shown in Table 11.

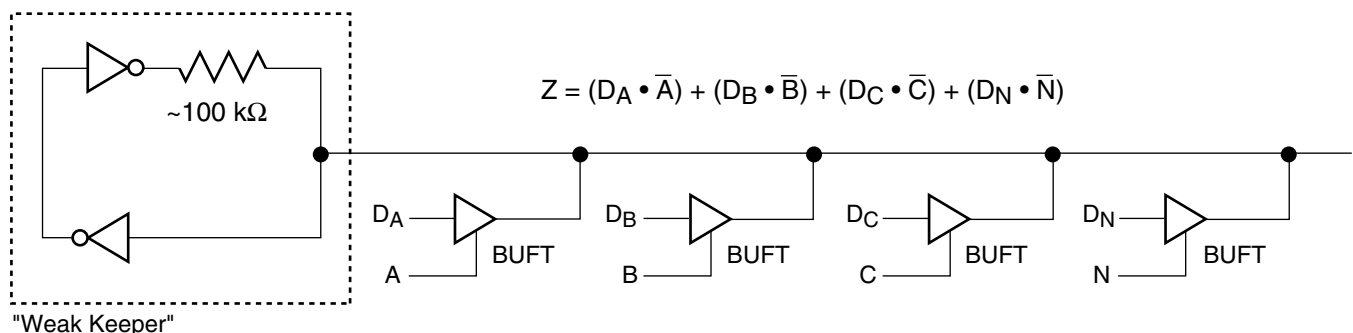
Three-State Buffer Example

Figure 18 shows how to use the 3-state buffers to implement a multiplexer. The selection is accomplished by the buffer 3-state signal.

Pay particular attention to the polarity of the T pin when using these buffers in a design. Active High 3-state (T) is identical to an active Low output enable, as shown in Table 11.

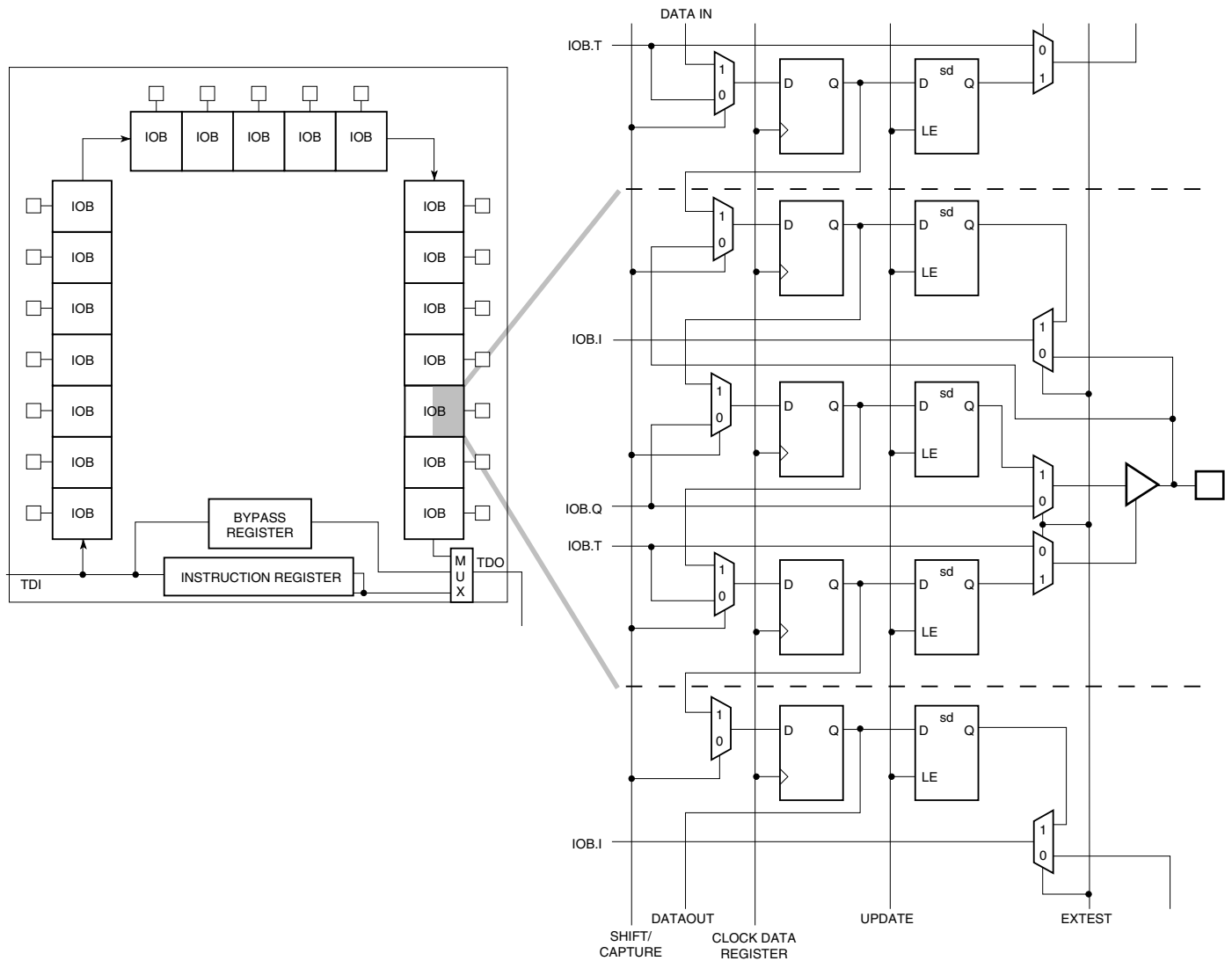
Table 11: Three-State Buffer Functionality

IN	T	OUT
X	1	Z
IN	0	IN



DS060_18_080400

Figure 18: 3-state Buffers Implement a Multiplexer



DS060_20_080400

Figure 20: Spartan/XL Boundary Scan Logic

Table 17: Spartan/XL Program Data

Device	XCS05		XCS10		XCS20		XCS30		XCS40	
Max System Gates	5,000		10,000		20,000		30,000		40,000	
CLBs (Row x Col.)	100 (10 x 10)		196 (14 x 14)		400 (20 x 20)		576 (24 x 24)		784 (28 x 28)	
I/Os	80		112		160		192		205 ⁽⁴⁾	
Part Number	XCS05	XCS05XL	XCS10	XCS10XL	XCS20	XCS20XL	XCS30	XCS30XL	XCS40	XCS40XL
Supply Voltage	5V	3.3V	5V	3.3V	5V	3.3V	5V	3.3V	5V	3.3V
Bits per Frame	126	127	166	167	226	227	266	267	306	307
Frames	428	429	572	573	788	789	932	933	1,076	1,077
Program Data	53,936	54,491	94,960	95,699	178,096	179,111	247,920	249,119	329,264	330,647
PROM Size (bits)	53,984	54,544	95,008	95,752	178,144	179,160	247,968	249,168	329,312	330,696
Express Mode PROM Size (bits)	-	79,072	-	128,488	-	221,056	-	298,696	-	387,856

Notes:

- Bits per Frame = (10 x number of rows) + 7 for the top + 13 for the bottom + 1 + 1 start bit + 4 error check bits (+1 for Spartan-XL device)
 Number of Frames = (36 x number of columns) + 26 for the left edge + 41 for the right edge + 1 (+ 1 for Spartan-XL device)
 Program Data = (Bits per Frame x Number of Frames) + 8 postamble bits
 PROM Size = Program Data + 40 (header) + 8, rounded up to the nearest byte
- The user can add more "1" bits as leading dummy bits in the header, or, if CRC = off, as trailing dummy bits at the end of any frame, following the four error check bits. However, the Length Count value **must** be adjusted for all such extra "one" bits, even for extra leading ones at the beginning of the header.
- Express mode adds 57 (XCS05XL, XCS10XL), or 53 (XCS20XL, XCS30XL, XCS40XL) bits per frame, + additional start-up bits.
- XCS40XL provided 224 max I/O in CS280 package discontinued by [PDN2004-01](#).

During Readback, 11 bits of the 16-bit checksum are added to the end of the Readback data stream. The checksum is computed using the CRC-16 CCITT polynomial, as shown in [Figure 29](#). The checksum consists of the 11 most significant bits of the 16-bit code. A change in the checksum indicates a change in the Readback bitstream. A comparison to a previous checksum is meaningful only if the readback

data is independent of the current device state. CLB outputs should not be included (Readback Capture option not used), and if RAM is present, the RAM content must be unchanged.

Statistically, one error out of 2048 might go undetected.

Readback Abort

When the Readback Abort option is selected, a High-to-Low transition on RDBK.TRIG terminates the Readback operation and prepares the logic to accept another trigger.

After an aborted Readback, additional clocks (up to one Readback clock per configuration frame) may be required to re-initialize the control logic. The status of Readback is indicated by the output control net RDBK.RIP. RDBK.RIP is High whenever a readback is in progress.

Clock Select

CCLK is the default clock. However, the user can insert another clock on RDBK.CLK. Readback control and data are clocked on rising edges of RDBK.CLK. If Readback must be inhibited for security reasons, the Readback control nets are simply not connected. RDBK.CLK is located in the lower right chip corner.

Violating the Maximum High and Low Time Specification for the Readback Clock

The Readback clock has a maximum High and Low time specification. In some cases, this specification cannot be

met. For example, if a processor is controlling Readback, an interrupt may force it to stop in the middle of a readback. This necessitates stopping the clock, and thus violating the specification.

The specification is mandatory only on clocking data at the end of a frame prior to the next start bit. The transfer mechanism will load the data to a shift register during the last six clock cycles of the frame, prior to the start bit of the following frame. This loading process is dynamic, and is the source of the maximum High and Low time requirements.

Therefore, the specification only applies to the six clock cycles prior to and including any start bit, including the clocks before the first start bit in the Readback data stream. At other times, the frame data is already in the register and the register is not dynamic. Thus, it can be shifted out just like a regular shift register.

The user must precisely calculate the location of the Readback data relative to the frame. The system must keep track of the position within a data frame, and disable interrupts before frame boundaries. Frame lengths and data formats are listed in [Table 16](#) and [Table 17](#).

Spartan Family Pin-to-Pin Input Parameter Guidelines

All devices are 100% functionally tested. Pin-to-pin timing parameters are derived from measuring external and internal test patterns and are guaranteed over worst-case operating conditions (supply voltage and junction temperature).

Listed below are representative values for typical pin locations and normal clock loading.

Spartan Family Primary and Secondary Setup and Hold

Symbol	Description	Device	Speed Grade		Units
			-4	-3	
			Min	Min	
Input Setup/Hold Times Using Primary Clock and IFF					
T _{PSUF} /T _{PHF}	No Delay	XCS05	1.2 / 1.7	1.8 / 2.5	ns
		XCS10	1.0 / 2.3	1.5 / 3.4	ns
		XCS20	0.8 / 2.7	1.2 / 4.0	ns
		XCS30	0.6 / 3.0	0.9 / 4.5	ns
		XCS40	0.4 / 3.5	0.6 / 5.2	ns
T _{PSU} /T _{PH}	With Delay	XCS05	4.3 / 0.0	6.0 / 0.0	ns
		XCS10	4.3 / 0.0	6.0 / 0.0	ns
		XCS20	4.3 / 0.0	6.0 / 0.0	ns
		XCS30	4.3 / 0.0	6.0 / 0.0	ns
		XCS40	5.3 / 0.0	6.8 / 0.0	ns
Input Setup/Hold Times Using Secondary Clock and IFF					
T _{SSUF} /T _{SHF}	No Delay	XCS05	0.9 / 2.2	1.5 / 3.0	ns
		XCS10	0.7 / 2.8	1.2 / 3.9	ns
		XCS20	0.5 / 3.2	0.9 / 4.5	ns
		XCS30	0.3 / 3.5	0.6 / 5.0	ns
		XCS40	0.1 / 4.0	0.3 / 5.7	ns
T _{SSU} /T _{SH}	With Delay	XCS05	4.0 / 0.0	5.7 / 0.0	ns
		XCS10	4.0 / 0.0	5.7 / 0.0	ns
		XCS20	4.0 / 0.5	5.7 / 0.5	ns
		XCS30	4.0 / 0.5	5.7 / 0.5	ns
		XCS40	5.0 / 0.0	6.5 / 0.0	ns

Notes:

1. Setup time is measured with the fastest route and the lightest load. Hold time is measured using the furthest distance and a reference load of one clock pin per IOB/CLB.
2. IFF = Input Flip-flop or Latch

Spartan Family IOB Output Switching Characteristic Guidelines

All devices are 100% functionally tested. Internal timing parameters are derived from measuring internal test patterns. Listed below are representative values. For more specific, more precise, and worst-case guaranteed data, use the values reported by the static timing analyzer (TRCE in the Xilinx Development System) and back-annotated to

the simulation netlist. These path delays, provided as a guideline, have been extracted from the static timing analyzer report. All timing parameters assume worst-case operating conditions (supply voltage and junction temperature). Values are expressed in nanoseconds unless otherwise noted.

Symbol	Description	Device	Speed Grade				Units
			-4		-3		
			Min	Max	Min	Max	
Clocks							
T _{CH}	Clock High	All devices	3.0	-	4.0	-	ns
T _{CL}	Clock Low	All devices	3.0	-	4.0	-	ns
Propagation Delays - TTL Outputs ^(1,2)							
T _{OKPOF}	Clock (OK) to Pad, fast	All devices	-	3.3	-	4.5	ns
T _{OKPOS}	Clock (OK to Pad, slew-rate limited	All devices	-	6.9	-	7.0	ns
T _{OPF}	Output (O) to Pad, fast	All devices	-	3.6	-	4.8	ns
T _{OPS}	Output (O) to Pad, slew-rate limited	All devices	-	7.2	-	7.3	ns
T _{TSHZ}	3-state to Pad High-Z (slew-rate independent)	All devices	-	3.0	-	3.8	ns
T _{TSONF}	3-state to Pad active and valid, fast	All devices	-	6.0	-	7.3	ns
T _{TSONS}	3-state to Pad active and valid, slew-rate limited	All devices	-	9.6	-	9.8	ns
Setup and Hold Times							
T _{OOK}	Output (O) to clock (OK) setup time	All devices	2.5	-	3.8	-	ns
T _{OKO}	Output (O) to clock (OK) hold time	All devices	0.0	-	0.0	-	ns
T _{ECOK}	Clock Enable (EC) to clock (OK) setup time	All devices	2.0	-	2.7	-	ns
T _{OKEC}	Clock Enable (EC) to clock (OK) hold time	All devices	0.0	-	0.5	-	ns
Global Set/Reset							
T _{MRW}	Minimum GSR pulse width	All devices	11.5		13.5		ns
T _{RPO}	Delay from GSR input to any Pad	XCS05	-	12.0	-	15.0	ns
		XCS10	-	12.5	-	15.7	ns
		XCS20	-	13.0	-	16.2	ns
		XCS30	-	13.5	-	16.9	ns
		XCS40	-	14.0	-	17.5	ns

Notes:

1. Delay adder for CMOS Outputs option (with fast slew rate option): for -3 speed grade, add 1.0 ns; for -4 speed grade, add 0.8 ns.
2. Delay adder for CMOS Outputs option (with slow slew rate option): for -3 speed grade, add 2.0 ns; for -4 speed grade, add 1.5 ns.
3. Output timing is measured at ~50% V_{CC} threshold, with 50 pF external capacitive loads including test fixture. Slew-rate limited output rise/fall times are approximately two times longer than fast output rise/fall times.
4. Voltage levels of unused pads, bonded or unbonded, must be valid logic levels. Each can be configured with the internal pull-up (default) or pull-down resistor, or configured as a driven output, or can be driven from an external source.

Spartan-XL Family Detailed Specifications

Definition of Terms

In the following tables, some specifications may be designated as Advance or Preliminary. These terms are defined as follows:

Advance: Initial estimates based on simulation and/or extrapolation from other speed grades, devices, or device families. Values are subject to change. Use as estimates, not for production.

Preliminary: Based on preliminary characterization. Further changes are not expected.

Unmarked: Specifications not identified as either Advance or Preliminary are to be considered Final.

Notwithstanding the definition of the above terms, all specifications are subject to change without notice.

Except for pin-to-pin input and output parameters, the AC parameter delay specifications included in this document are derived from measuring internal test patterns. All specifications are representative of worst-case supply voltage and junction temperature conditions. The parameters included are common to popular designs and typical applications.

Spartan-XL Family Absolute Maximum Ratings⁽¹⁾

Symbol	Description		Value	Units
V_{CC}	Supply voltage relative to GND		−0.5 to 4.0	V
V_{IN}	Input voltage relative to GND	5V Tolerant I/O Checked ^(2, 3)	−0.5 to 5.5	V
		Not 5V Tolerant I/Os ^(4, 5)	−0.5 to $V_{CC} + 0.5$	V
V_{TS}	Voltage applied to 3-state output	5V Tolerant I/O Checked ^(2, 3)	−0.5 to 5.5	V
		Not 5V Tolerant I/Os ^(4, 5)	−0.5 to $V_{CC} + 0.5$	V
T_{STG}	Storage temperature (ambient)		−65 to +150	°C
T_J	Junction temperature	Plastic packages	+125	°C

Notes:

- Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those listed under Operating Conditions is not implied. Exposure to Absolute Maximum Ratings conditions for extended periods of time may affect device reliability.
- With 5V Tolerant I/Os selected, the Maximum DC overshoot must be limited to either +5.5V or 10 mA and undershoot (below GND) must be limited to either 0.5V or 10 mA, whichever is easier to achieve.
- With 5V Tolerant I/Os selected, the Maximum AC (during transitions) conditions are as follows; the device pins may undershoot to −2.0V or overshoot to + 7.0V, provided this overshoot or undershoot lasts no more than 11 ns with a forcing current no greater than 100 mA.
- Without 5V Tolerant I/Os selected, the Maximum DC overshoot or undershoot must be limited to either 0.5V or 10 mA, whichever is easier to achieve.
- Without 5V Tolerant I/Os selected, the Maximum AC conditions are as follows; the device pins may undershoot to −2.0V or overshoot to $V_{CC} + 2.0V$, provided this overshoot or undershoot lasts no more than 11 ns with a forcing current no greater than 100 mA.
- For soldering guidelines, see the Package Information on the Xilinx website.

Spartan-XL Family Recommended Operating Conditions

Symbol	Description		Min	Max	Units
V_{CC}	Supply voltage relative to GND, $T_J = 0^{\circ}\text{C}$ to $+85^{\circ}\text{C}$	Commercial	3.0	3.6	V
	Supply voltage relative to GND, $T_J = -40^{\circ}\text{C}$ to $+100^{\circ}\text{C}$ ⁽¹⁾	Industrial	3.0	3.6	V
V_{IH}	High-level input voltage ⁽²⁾		50% of V_{CC}	5.5	V
V_{IL}	Low-level input voltage ⁽²⁾		0	30% of V_{CC}	V
T_{IN}	Input signal transition time		-	250	ns

Notes:

- At junction temperatures above those listed as Operating Conditions, all delay parameters increase by 0.35% per °C.
- Input and output measurement threshold is ~50% of V_{CC} .

Spartan-XL Family CLB RAM Synchronous (Edge-Triggered) Write Operation Guidelines

All devices are 100% functionally tested. Internal timing parameters are derived from measuring internal test patterns. Listed below are representative values. For more specific, more precise, and worst-case guaranteed data, use the values reported by the static timing analyzer (TRCE

in the Xilinx Development System) and back-annotated to the simulation netlist. All timing parameters assume worst-case operating conditions (supply voltage and junction temperature). Values apply to all Spartan-XL devices and are expressed in nanoseconds unless otherwise noted.

Symbol	Single Port RAM	Size ⁽¹⁾	Speed Grade				Units
			-5		-4		
			Min	Max	Min	Max	
Write Operation							
T _{WCS}	Address write cycle time (clock K period)	16x2	7.7	-	8.4	-	ns
T _{WCTS}		32x1	7.7	-	8.4	-	ns
T _{WPS}	Clock K pulse width (active edge)	16x2	3.1	-	3.6	-	ns
T _{WPTS}		32x1	3.1	-	3.6	-	ns
T _{ASS}	Address setup time before clock K	16x2	1.3	-	1.5	-	ns
T _{ASTS}		32x1	1.5	-	1.7	-	ns
T _{DSS}	DIN setup time before clock K	16x2	1.5	-	1.7	-	ns
T _{DSTS}		32x1	1.8	-	2.1	-	ns
T _{WSS}	WE setup time before clock K	16x2	1.4	-	1.6	-	ns
T _{WSTS}		32x1	1.3	-	1.5	-	ns
	All hold times after clock K	16x2	0.0	-	0.0	-	ns
T _{WOS}	Data valid after clock K	32x1	-	4.5	-	5.3	ns
T _{WOTS}		16x2	-	5.4	-	6.3	ns
Read Operation							
T _{RC}	Address read cycle time	16x2	2.6	-	3.1	-	ns
T _{RCT}		32x1	3.8	-	5.5	-	ns
T _{ILO}	Data Valid after address change (no Write Enable)	16x2	-	1.0	-	1.1	ns
T _{IHO}		32x1	-	1.7	-	2.0	ns
T _{ICK}	Address setup time before clock K	16x2	0.6	-	0.7	-	ns
T _{IHCK}		32x1	1.3	-	1.6	-	ns

Notes:

1. Timing for 16 x 1 RAM option is identical to 16 x 2 RAM timing.

Spartan-XL Family CLB RAM Synchronous (Edge-Triggered) Write Operation Guidelines (cont.)

All devices are 100% functionally tested. Internal timing parameters are derived from measuring internal test patterns. Listed below are representative values. For more specific, more precise, and worst-case guaranteed data, use the values reported by the static timing analyzer (TRCE

in the Xilinx Development System) and back-annotated to the simulation netlist. All timing parameters assume worst-case operating conditions (supply voltage and junction temperature). Values apply to all Spartan-XL devices and are expressed in nanoseconds unless otherwise noted.

Symbol	Dual Port RAM	Size	-5		-4		Units
			Min	Max	Min	Max	
Write Operation ⁽¹⁾							
T _{WCDS}	Address write cycle time (clock K period)	16x1	7.7	-	8.4	-	ns
T _{WPDS}	Clock K pulse width (active edge)	16x1	3.1	-	3.6	-	ns
T _{ASDS}	Address setup time before clock K	16x1	1.3	-	1.5	-	ns
T _{DSDS}	DIN setup time before clock K	16x1	1.7	-	2.0	-	ns
T _{WSDS}	WE setup time before clock K	16x1	1.4	-	1.6	-	ns
	All hold times after clock K	16x1	0	-	0	-	ns
T _{WODS}	Data valid after clock K	16x1	-	5.2	-	6.1	ns

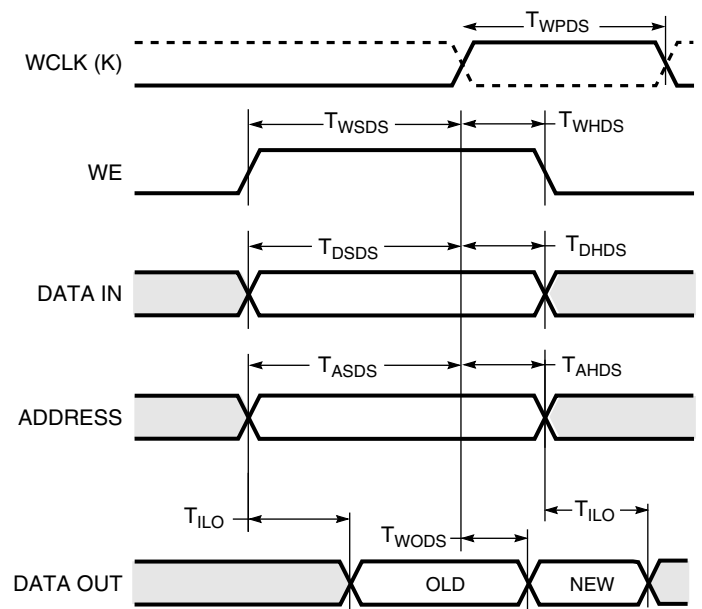
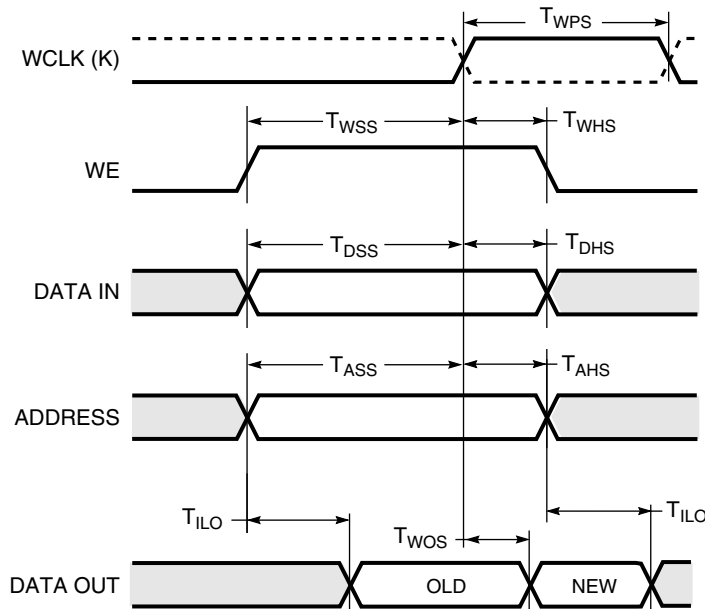
Notes:

1. Read Operation timing for 16 x 1 dual-port RAM option is identical to 16 x 2 single-port RAM timing

Spartan-XL Family CLB RAM Synchronous (Edge-Triggered) Write Timing

Single Port

Dual Port



DS060_34_011300

Spartan-XL Family Pin-to-Pin Input Parameter Guidelines

All devices are 100% functionally tested. Pin-to-pin timing parameters are derived from measuring external and internal test patterns and are guaranteed over worst-case operating conditions (supply voltage and junction temperature). Listed below are representative values for typical pin locations and normal clock loading.

ating conditions (supply voltage and junction temperature). Listed below are representative values for typical pin locations and normal clock loading.

Spartan-XL Family Setup and Hold

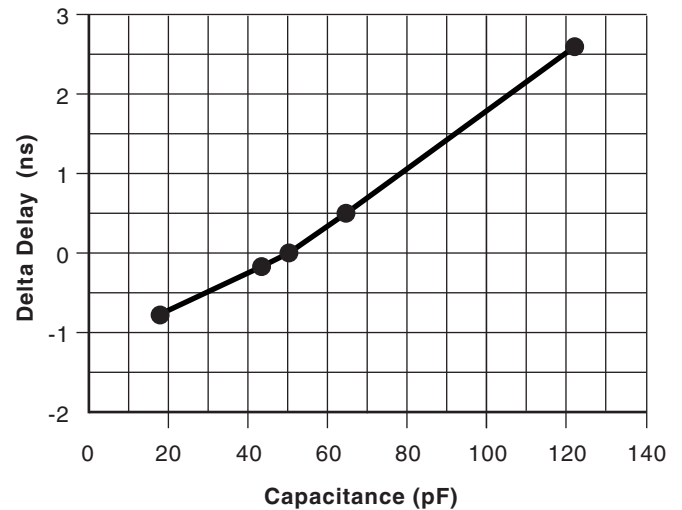
Symbol	Description	Device	Speed Grade		Units
			-5	-4	
			Max	Max	
Input Setup/Hold Times Using Global Clock and IFF					
T _{SUF} /T _{HF}	No Delay	XCS05XL	1.1/2.0	1.6/2.6	ns
		XCS10XL	1.0/2.2	1.5/2.8	ns
		XCS20XL	0.9/2.4	1.4/3.0	ns
		XCS30XL	0.8/2.6	1.3/3.2	ns
		XCS40XL	0.7/2.8	1.2/3.4	ns
T _{SU} /T _H	Full Delay	XCS05XL	3.9/0.0	5.1/0.0	ns
		XCS10XL	4.1/0.0	5.3/0.0	ns
		XCS20XL	4.3/0.0	5.5/0.0	ns
		XCS30XL	4.5/0.0	5.7/0.0	ns
		XCS40XL	4.7/0.0	5.9/0.0	ns

Notes:

1. IFF = Input Flip-Flop or Latch
2. Setup time is measured with the fastest route and the lightest load. Hold time is measured using the furthest distance and a reference load of one clock pin per IOB/CLB.

Capacitive Load Factor

Figure 35 shows the relationship between I/O output delay and load capacitance. It allows a user to adjust the specified output delay if the load capacitance is different than 50 pF. For example, if the actual load capacitance is 120 pF, add 2.5 ns to the specified delay. If the load capacitance is 20 pF, subtract 0.8 ns from the specified output delay. Figure 35 is usable over the specified operating conditions of voltage and temperature and is independent of the output slew rate control.



DS060_35_080400

Figure 35: Delay Factor at Various Capacitive Loads

XCS05 and XCS05XL Device Pinouts

XCS05/XL Pad Name	PC84 ⁽⁴⁾	VQ100	Bndry Scan
I/O	P70	P71	238 ⁽³⁾
I/O (D0 ⁽²⁾ , DIN)	P71	P72	241 ⁽³⁾
I/O, SGCK4 ⁽¹⁾ , GCK6 ⁽²⁾ (DOUT)	P72	P73	244 ⁽³⁾
CCLK	P73	P74	-
VCC	P74	P75	-
O, TDO	P75	P76	0
GND	P76	P77	-
I/O	P77	P78	2
I/O, PGCK4 ⁽¹⁾ , GCK7 ⁽²⁾	P78	P79	5
I/O (CS1 ⁽²⁾)	P79	P80	8
I/O	P80	P81	11
I/O	P81	P82	14
I/O	P82	P83	17
I/O	-	P84	20
I/O	-	P85	23
I/O	P83	P86	26
I/O	P84	P87	29
GND	P1	P88	-

Notes:

1. 5V Spartan family only
2. 3V Spartan-XL family only
3. The "PWRDWN" on the XCS05XL is not part of the Boundary Scan chain. For the XCS05XL, subtract 1 from all Boundary Scan numbers from GCK3 on (127 and higher).
4. PC84 package discontinued by [PDN2004-01](#)

XCS10 and XCS10XL Device Pinouts

XCS10/XL Pad Name	PC84 ⁽⁴⁾	VQ100	CS144 ^(2,4)	TQ144	Bndry Scan
VCC	P2	P89	D7	P128	-
I/O	P3	P90	A6	P129	44
I/O	P4	P91	B6	P130	47
I/O	-	P92	C6	P131	50
I/O	-	P93	D6	P132	53
I/O	P5	P94	A5	P133	56
I/O	P6	P95	B5	P134	59
I/O	-	-	C5	P135	62
I/O	-	-	D5	P136	65
GND	-	-	A4	P137	-
I/O	P7	P96	B4	P138	68
I/O	P8	P97	C4	P139	71
I/O	-	-	A3	P140	74
I/O	-	-	B3	P141	77
I/O	P9	P98	C3	P142	80

XCS10 and XCS10XL Device Pinouts

XCS10/XL Pad Name	PC84 ⁽⁴⁾	VQ100	CS144 ^(2,4)	TQ144	Bndry Scan
I/O, SGCK1 ⁽¹⁾ GCK8 ⁽²⁾	P10	P99	A2	P143	83
VCC	P11	P100	B2	P144	-
GND	P12	P1	A1	P1	-
I/O, PGCK1 ⁽¹⁾ GCK1 ⁽²⁾	P13	P2	B1	P2	86
I/O	P14	P3	C2	P3	89
I/O	-	-	C1	P4	92
I/O	-	-	D4	P5	95
I/O, TDI	P15	P4	D3	P6	98
I/O, TCK	P16	P5	D2	P7	101
GND	-	-	D1	P8	-
I/O	-	-	E4	P9	104
I/O	-	-	E3	P10	107
I/O, TMS	P17	P6	E2	P11	110
I/O	P18	P7	E1	P12	113
I/O	-	-	F4	P13	116
I/O	-	P8	F3	P14	119
I/O	P19	P9	F2	P15	122
I/O	P20	P10	F1	P16	125
GND	P21	P11	G2	P17	-
VCC	P22	P12	G1	P18	-
I/O	P23	P13	G3	P19	128
I/O	P24	P14	G4	P20	131
I/O	-	P15	H1	P21	134
I/O	-	-	H2	P22	137
I/O	P25	P16	H3	P23	140
I/O	P26	P17	H4	P24	143
I/O	-	-	J1	P25	146
I/O	-	-	J2	P26	149
GND	-	-	J3	P27	-
I/O	P27	P18	J4	P28	152
I/O	-	P19	K1	P29	155
I/O	-	-	K2	P30	158
I/O	-	-	K3	P31	161
I/O	P28	P20	L1	P32	164
I/O, SGCK2 ⁽¹⁾ GCK2 ⁽²⁾	P29	P21	L2	P33	167
Not Connected ⁽¹⁾ M1 ⁽²⁾	P30	P22	L3	P34	170
GND	P31	P23	M1	P35	-
MODE ⁽¹⁾ , M0 ⁽²⁾	P32	P24	M2	P36	173

XCS10 and XCS10XL Device Pinouts

XCS10/XL Pad Name	PC84 ⁽⁴⁾	VQ100	CS144 ^(2,4)	TQ144	Bndry Scan
VCC	P33	P25	N1	P37	-
Not Connect-ed ⁽¹⁾	P34	P26	N2	P38	174 ⁽¹⁾
PWRDWN ⁽²⁾					
I/O, PGCK2 ⁽¹⁾ GCK3 ⁽²⁾	P35	P27	M3	P39	175 ⁽³⁾
I/O (HDC)	P36	P28	N3	P40	178 ⁽³⁾
I/O	-	-	K4	P41	181 ⁽³⁾
I/O	-	-	L4	P42	184 ⁽³⁾
I/O	-	P29	M4	P43	187 ⁽³⁾
I/O (LDC)	P37	P30	N4	P44	190 ⁽³⁾
GND	-	-	K5	P45	-
I/O	-	-	L5	P46	193 ⁽³⁾
I/O	-	-	M5	P47	196 ⁽³⁾
I/O	P38	P31	N5	P48	199 ⁽³⁾
I/O	P39	P32	K6	P49	202 ⁽³⁾
I/O	-	P33	L6	P50	205 ⁽³⁾
I/O	-	P34	M6	P51	208 ⁽³⁾
I/O	P40	P35	N6	P52	211 ⁽³⁾
I/O (INIT)	P41	P36	M7	P53	214 ⁽³⁾
VCC	P42	P37	N7	P54	-
GND	P43	P38	L7	P55	-
I/O	P44	P39	K7	P56	217 ⁽³⁾
I/O	P45	P40	N8	P57	220 ⁽³⁾
I/O	-	P41	M8	P58	223 ⁽³⁾
I/O	-	P42	L8	P59	226 ⁽³⁾
I/O	P46	P43	K8	P60	229 ⁽³⁾
I/O	P47	P44	N9	P61	232 ⁽³⁾
I/O	-	-	M9	P62	235 ⁽³⁾
I/O	-	-	L9	P63	238 ⁽³⁾
GND	-	-	K9	P64	-
I/O	P48	P45	N10	P65	241 ⁽³⁾
I/O	P49	P46	M10	P66	244 ⁽³⁾
I/O	-	-	L10	P67	247 ⁽³⁾
I/O	-	-	N11	P68	250 ⁽³⁾
I/O	P50	P47	M11	P69	253 ⁽³⁾
I/O, SGCK3 ⁽¹⁾ GCK4 ⁽²⁾	P51	P48	L11	P70	256 ⁽³⁾
GND	P52	P49	N12	P71	-
DONE	P53	P50	M12	P72	-
VCC	P54	P51	N13	P73	-
PROGRAM	P55	P52	M13	P74	-
I/O (D7 ⁽²⁾)	P56	P53	L12	P75	259 ⁽³⁾

XCS10 and XCS10XL Device Pinouts

XCS10/XL Pad Name	PC84 ⁽⁴⁾	VQ100	CS144 ^(2,4)	TQ144	Bndry Scan
I/O, PGCK3 ⁽¹⁾ GCK5 ⁽²⁾	P57	P54	L13	P76	262 ⁽³⁾
I/O	-	-	K10	P77	265 ⁽³⁾
I/O	-	-	K11	P78	268 ⁽³⁾
I/O (D6 ⁽²⁾)	P58	P55	K12	P79	271 ⁽³⁾
I/O	-	P56	K13	P80	274 ⁽³⁾
GND	-	-	J10	P81	-
I/O	-	-	J11	P82	277 ⁽³⁾
I/O	-	-	J12	P83	280 ⁽³⁾
I/O (D5 ⁽²⁾)	P59	P57	J13	P84	283 ⁽³⁾
I/O	P60	P58	H10	P85	286 ⁽³⁾
I/O	-	P59	H11	P86	289 ⁽³⁾
I/O	-	P60	H12	P87	292 ⁽³⁾
I/O (D4 ⁽²⁾)	P61	P61	H13	P88	295 ⁽³⁾
I/O	P62	P62	G12	P89	298 ⁽³⁾
VCC	P63	P63	G13	P90	-
GND	P64	P64	G11	P91	-
I/O (D3 ⁽²⁾)	P65	P65	G10	P92	301 ⁽³⁾
I/O	P66	P66	F13	P93	304 ⁽³⁾
I/O	-	P67	F12	P94	307 ⁽³⁾
I/O	-	-	F11	P95	310 ⁽³⁾
I/O (D2 ⁽²⁾)	P67	P68	F10	P96	313 ⁽³⁾
I/O	P68	P69	E13	P97	316 ⁽³⁾
I/O	-	-	E12	P98	319 ⁽³⁾
I/O	-	-	E11	P99	322 ⁽³⁾
GND	-	-	E10	P100	-
I/O (D1 ⁽²⁾)	P69	P70	D13	P101	325 ⁽³⁾
I/O	P70	P71	D12	P102	328 ⁽³⁾
I/O	-	-	D11	P103	331 ⁽³⁾
I/O	-	-	C13	P104	334 ⁽³⁾
I/O (D0 ⁽²⁾ , DIN)	P71	P72	C12	P105	337 ⁽³⁾
I/O, SGCK4 ⁽¹⁾ GCK6 ⁽²⁾ (DOUT)	P72	P73	C11	P106	340 ⁽³⁾
CCLK	P73	P74	B13	P107	-
VCC	P74	P75	B12	P108	-
O, TDO	P75	P76	A13	P109	0
GND	P76	P77	A12	P110	-
I/O	P77	P78	B11	P111	2
I/O, PGCK4 ⁽¹⁾ GCK7 ⁽²⁾	P78	P79	A11	P112	5
I/O	-	-	D10	P113	8
I/O	-	-	C10	P114	11
I/O (CS1 ⁽²⁾)	P79	P80	B10	P115	14

XCS30 and XCS30XL Device Pinouts (Continued)

XCS30/XL Pad Name	VQ100 ⁽⁵⁾	TQ144	PQ208	PQ240	BG256 ⁽⁵⁾	CS280 ^(2,5)	Bndry Scan
I/O	-	P5	P5	P5	D3	C1	155
I/O, TDI	P4	P6	P6	P6	E4	D4	158
I/O, TCK	P5	P7	P7	P7	C1	D3	161
I/O	-	-	P8	P8	D1	E2	164
I/O	-	-	P9	P9	E3	E4	167
I/O	-	-	P10	P10	E2	E1	170
I/O	-	-	P11	P11	E1	F5	173
I/O	-	-	P12	P12	F3	F3	176
I/O	-	-	-	P13	F2	F2	179
GND	-	P8	P13	P14	GND ⁽⁴⁾	GND ⁽⁴⁾	-
I/O	-	P9	P14	P15	G3	F4	182
I/O	-	P10	P15	P16	G2	F1	185
I/O, TMS	P6	P11	P16	P17	G1	G3	188
I/O	P7	P12	P17	P18	H3	G2	191
VCC	-	-	P18	P19	VCC ⁽⁴⁾	G1	-
I/O	-	-	-	P20	H2	G4	194
I/O	-	-	-	P21	H1	H1	197
I/O	-	-	P19	P23	J2	H4	200
I/O	-	-	P20	P24	J1	J1	203
I/O	-	P13	P21	P25	K2	J2	206
I/O	P8	P14	P22	P26	K3	J3	209
I/O	P9	P15	P23	P27	K1	J4	212
I/O	P10	P16	P24	P28	L1	K1	215
GND	P11	P17	P25	P29	GND ⁽⁴⁾	GND ⁽⁴⁾	-
VCC	P12	P18	P26	P30	VCC ⁽⁴⁾	K2	-
I/O	P13	P19	P27	P31	L2	K3	218
I/O	P14	P20	P28	P32	L3	K4	221
I/O	P15	P21	P29	P33	L4	K5	224
I/O	-	P22	P30	P34	M1	L1	227
I/O	-	-	P31	P35	M2	L2	230
I/O	-	-	P32	P36	M3	L3	233
I/O	-	-	-	P38	N1	M2	236
I/O	-	-	-	P39	N2	M3	239
VCC	-	-	P33	P40	VCC ⁽⁴⁾	M4	-
I/O	P16	P23	P34	P41	P1	N1	242
I/O	P17	P24	P35	P42	P2	N2	245
I/O	-	P25	P36	P43	R1	N3	248
I/O	-	P26	P37	P44	P3	N4	251
GND	-	P27	P38	P45	GND ⁽⁴⁾	GND ⁽⁴⁾	-
I/O	-	-	-	P46	T1	P1	254
I/O	-	-	P39	P47	R3	P2	257
I/O	-	-	P40	P48	T2	P3	260
I/O	-	-	P41	P49	U1	P4	263
I/O	-	-	P42	P50	T3	P5	266
I/O	-	-	P43	P51	U2	R1	269

XCS30 and XCS30XL Device Pinouts (Continued)

XCS30/XL Pad Name	VQ100 ⁽⁵⁾	TQ144	PQ208	PQ240	BG256 ⁽⁵⁾	CS280 ^(2,5)	Bndry Scan
I/O	-	-	P85	P97	U12	T11	382 ⁽³⁾
I/O	-	-	-	P99	V13	U12	385 ⁽³⁾
I/O	-	-	-	P100	Y14	T12	388 ⁽³⁾
VCC	-	-	P86	P101	VCC ⁽⁴⁾	W13	-
I/O	P43	P60	P87	P102	Y15	V13	391 ⁽³⁾
I/O	P44	P61	P88	P103	V14	U13	394 ⁽³⁾
I/O	-	P62	P89	P104	W15	T13	397 ⁽³⁾
I/O	-	P63	P90	P105	Y16	W14	400 ⁽³⁾
GND	-	P64	P91	P106	GND ⁽⁴⁾	GND ⁽⁴⁾	-
I/O	-	-	-	P107	V15	V14	403 ⁽³⁾
I/O	-	-	P92	P108	W16	U14	406 ⁽³⁾
I/O	-	-	P93	P109	Y17	T14	409 ⁽³⁾
I/O	-	-	P94	P110	V16	R14	412 ⁽³⁾
I/O	-	-	P95	P111	W17	W15	415 ⁽³⁾
I/O	-	-	P96	P112	Y18	U15	418 ⁽³⁾
I/O	P45	P65	P97	P113	U16	V16	421 ⁽³⁾
I/O	P46	P66	P98	P114	V17	U16	424 ⁽³⁾
I/O	-	P67	P99	P115	W18	W17	427 ⁽³⁾
I/O	-	P68	P100	P116	Y19	W18	430 ⁽³⁾
I/O	P47	P69	P101	P117	V18	V17	433 ⁽³⁾
I/O, SGCK3 ⁽¹⁾ , GCK4 ⁽²⁾	P48	P70	P102	P118	W19	V18	436 ⁽³⁾
GND	P49	P71	P103	P119	GND ⁽⁴⁾	GND ⁽⁴⁾	-
DONE	P50	P72	P104	P120	Y20	W19	-
VCC	P51	P73	P105	P121	VCC ⁽⁴⁾	U17	-
PROGRAM	P52	P74	P106	P122	V19	U18	-
I/O (D7 ⁽²⁾)	P53	P75	P107	P123	U19	V19	439 ⁽³⁾
I/O, PGCK3 ⁽¹⁾ , GCK5 ⁽²⁾	P54	P76	P108	P124	U18	U19	442 ⁽³⁾
I/O	-	P77	P109	P125	T17	T16	445 ⁽³⁾
I/O	-	P78	P110	P126	V20	T17	448 ⁽³⁾
I/O	-	-	-	P127	U20	T18	451 ⁽³⁾
I/O	-	-	P111	P128	T18	T19	454 ⁽³⁾
I/O (D6 ⁽²⁾)	P55	P79	P112	P129	T19	R16	457 ⁽³⁾
I/O	P56	P80	P113	P130	T20	R19	460 ⁽³⁾
I/O	-	-	P114	P131	R18	P15	463 ⁽³⁾
I/O	-	-	P115	P132	R19	P17	466 ⁽³⁾
I/O	-	-	P116	P133	R20	P18	469 ⁽³⁾
I/O	-	-	P117	P134	P18	P16	472 ⁽³⁾
GND	-	P81	P118	P135	GND ⁽⁴⁾	GND ⁽⁴⁾	-
I/O	-	-	-	P136	P20	P19	475 ⁽³⁾
I/O	-	-	-	P137	N18	N17	478 ⁽³⁾
I/O	-	P82	P119	P138	N19	N18	481 ⁽³⁾
I/O	-	P83	P120	P139	N20	N19	484 ⁽³⁾
VCC	-	-	P121	P140	VCC ⁽⁴⁾	N16	-
I/O (D5 ⁽²⁾)	P57	P84	P122	P141	M17	M19	487 ⁽³⁾
I/O	P58	P85	P123	P142	M18	M17	490 ⁽³⁾

XCS40 and XCS40XL Device Pinouts

XCS40/XL Pad Name	PQ208	PQ240	BG256	CS280 ^(2,5)	Bndry Scan
GND	P25	P29	GND ⁽⁴⁾	GND ⁽⁴⁾	-
VCC	P26	P30	VCC ⁽⁴⁾	VCC ⁽⁴⁾	-
I/O	P27	P31	L2	K3	254
I/O	P28	P32	L3	K4	257
I/O	P29	P33	L4	K5	260
I/O	P30	P34	M1	L1	263
I/O	P31	P35	M2	L2	266
I/O	P32	P36	M3	L3	269
I/O	-	-	M4	L4	272
I/O	-	-	-	M1	275
I/O	-	P38	N1	M2	278
I/O	-	P39	N2	M3	281
VCC	P33	P40	VCC ⁽⁴⁾	VCC ⁽⁴⁾	-
I/O	P34	P41	P1	N1	284
I/O	P35	P42	P2	N2	287
I/O	P36	P43	R1	N3	290
I/O	P37	P44	P3	N4	293
GND	P38	P45	GND ⁽⁴⁾	GND ⁽⁴⁾	-
I/O	-	P46	T1	P1	296
I/O	P39	P47	R3	P2	299
I/O	P40	P48	T2	P3	302
I/O	P41	P49	U1	P4	305
I/O	P42	P50	T3	P5	308
I/O	P43	P51	U2	R1	311
I/O	-	-	-	R2	314
I/O	-	-	-	R4	317
I/O	P44	P52	V1	T1	320
I/O	P45	P53	T4	T2	323
I/O	P46	P54	U3	T3	326
I/O	P47	P55	V2	U1	329
I/O	P48	P56	W1	V1	332
I/O, SGCK2 ⁽¹⁾ , GCK2 ⁽²⁾	P49	P57	V3	U2	335
Not Connected ⁽¹⁾ M1 ⁽²⁾	P50	P58	W2	V2	338
GND	P51	P59	GND ⁽⁴⁾	GND ⁽⁴⁾	-
MODE ⁽¹⁾ , M0 ⁽²⁾	P52	P60	Y1	W1	341
VCC	P53	P61	VCC ⁽⁴⁾	VCC ⁽⁴⁾	-
Not Connected ⁽¹⁾ PWRDWN ⁽²⁾	P54	P62	W3	V3	342 ⁽¹⁾
I/O, PGCK2 ⁽¹⁾ , GCK3 ⁽²⁾	P55	P63	Y2	W2	343 ⁽³⁾

XCS40 and XCS40XL Device Pinouts

XCS40/XL Pad Name	PQ208	PQ240	BG256	CS280 ^(2,5)	Bndry Scan
I/O (HDC)	P56	P64	W4	W3	346 ⁽³⁾
I/O	P57	P65	V4	T4	349 ⁽³⁾
I/O	P58	P66	U5	U4	352 ⁽³⁾
I/O	P59	P67	Y3	V4	355 ⁽³⁾
I/O (LDC)	P60	P68	Y4	W4	358 ⁽³⁾
I/O	-	-	-	R5	361 ⁽³⁾
I/O	-	-	-	U5	364 ⁽³⁾
I/O	P61	P69	V5	T5	367 ⁽³⁾
I/O	P62	P70	W5	W5	370 ⁽³⁾
I/O	P63	P71	Y5	R6	373 ⁽³⁾
I/O	P64	P72	V6	U6	376 ⁽³⁾
I/O	P65	P73	W6	V6	379 ⁽³⁾
I/O	-	P74	Y6	T6	382 ⁽³⁾
GND	P66	P75	GND ⁽⁴⁾	GND ⁽⁴⁾	-
I/O	P67	P76	W7	W6	385 ⁽³⁾
I/O	P68	P77	Y7	U7	388 ⁽³⁾
I/O	P69	P78	V8	V7	391 ⁽³⁾
I/O	P70	P79	W8	W7	394 ⁽³⁾
VCC	P71	P80	VCC ⁽⁴⁾	VCC ⁽⁴⁾	-
I/O	P72	P81	Y8	W8	397 ⁽³⁾
I/O	P73	P82	U9	U8	400 ⁽³⁾
I/O	-	-	V9	V8	403 ⁽³⁾
I/O	-	-	W9	T8	406 ⁽³⁾
I/O	-	P84	Y9	W9	409 ⁽³⁾
I/O	-	P85	W10	V9	412 ⁽³⁾
I/O	P74	P86	V10	U9	415 ⁽³⁾
I/O	P75	P87	Y10	T9	418 ⁽³⁾
I/O	P76	P88	Y11	W10	421 ⁽³⁾
I/O (INIT)	P77	P89	W11	V10	424 ⁽³⁾
VCC	P78	P90	VCC ⁽⁴⁾	VCC ⁽⁴⁾	VCC ⁽⁴⁾
GND	P79	P91	GND ⁽⁴⁾	GND ⁽⁴⁾	-
I/O	P80	P92	V11	T10	427 ⁽³⁾
I/O	P81	P93	U11	R10	430 ⁽³⁾
I/O	P82	P94	Y12	W11	433 ⁽³⁾
I/O	P83	P95	W12	V11	436 ⁽³⁾
I/O	P84	P96	V12	U11	439 ⁽³⁾
I/O	P85	P97	U12	T11	442 ⁽³⁾
I/O	-	-	Y13	W12	445 ⁽³⁾
I/O	-	-	W13	V12	448 ⁽³⁾
I/O	-	P99	V13	U12	451 ⁽³⁾
I/O	-	P100	Y14	T12	454 ⁽³⁾
VCC	P86	P101	VCC ⁽⁴⁾	VCC ⁽⁴⁾	-
I/O	P87	P102	Y15	V13	457 ⁽³⁾
I/O	P88	P103	V14	U13	460 ⁽³⁾
I/O	P89	P104	W15	T13	463 ⁽³⁾

XCS40 and XCS40XL Device Pinouts

XCS40/XL Pad Name	PQ208	PQ240	BG256	CS280 ^(2,5)	Bndry Scan
I/O	P90	P105	Y16	W14	466 ⁽³⁾
GND	P91	P106	GND ⁽⁴⁾	GND ⁽⁴⁾	-
I/O	-	P107	V15	V14	469 ⁽³⁾
I/O	P92	P108	W16	U14	472 ⁽³⁾
I/O	P93	P109	Y17	T14	475 ⁽³⁾
I/O	P94	P110	V16	R14	478 ⁽³⁾
I/O	P95	P111	W17	W15	481 ⁽³⁾
I/O	P96	P112	Y18	U15	484 ⁽³⁾
I/O	-	-	-	T15	487 ⁽³⁾
I/O	-	-	-	W16	490 ⁽³⁾
I/O	P97	P113	U16	V16	493 ⁽³⁾
I/O	P98	P114	V17	U16	496 ⁽³⁾
I/O	P99	P115	W18	W17	499 ⁽³⁾
I/O	P100	P116	Y19	W18	502 ⁽³⁾
I/O	P101	P117	V18	V17	505 ⁽³⁾
I/O, SGCK3 ⁽¹⁾ , GCK4 ⁽²⁾	P102	P118	W19	V18	508 ⁽³⁾
GND	P103	P119	GND ⁽⁴⁾	GND ⁽⁴⁾	-
DONE	P104	P120	Y20	W19	-
VCC	P105	P121	VCC ⁽⁴⁾	VCC ⁽⁴⁾	-
PROGRAM	P106	P122	V19	U18	-
I/O (D7 ⁽²⁾)	P107	P123	U19	V19	511 ⁽³⁾
I/O, PGCK3 ⁽¹⁾ , GCK5 ⁽²⁾	P108	P124	U18	U19	514 ⁽³⁾
I/O	P109	P125	T17	T16	517 ⁽³⁾
I/O	P110	P126	V20	T17	520 ⁽³⁾
I/O	-	P127	U20	T18	523 ⁽³⁾
I/O	P111	P128	T18	T19	526 ⁽³⁾
I/O	-	-	-	R15	529 ⁽³⁾
I/O	-	-	-	R17	523 ⁽³⁾
I/O (D6 ⁽²⁾)	P112	P129	T19	R16	535 ⁽³⁾
I/O	P113	P130	T20	R19	538 ⁽³⁾
I/O	P114	P131	R18	P15	541 ⁽³⁾
I/O	P115	P132	R19	P17	544 ⁽³⁾
I/O	P116	P133	R20	P18	547 ⁽³⁾
I/O	P117	P134	P18	P16	550 ⁽³⁾
GND	P118	P135	GND ⁽⁴⁾	GND ⁽⁴⁾	-
I/O	-	P136	P20	P19	553 ⁽³⁾
I/O	-	P137	N18	N17	556 ⁽³⁾
I/O	P119	P138	N19	N18	559 ⁽³⁾
I/O	P120	P139	N20	N19	562 ⁽³⁾
VCC	P121	P140	VCC ⁽⁴⁾	VCC ⁽⁴⁾	-
I/O (D5 ⁽²⁾)	P122	P141	M17	M19	565 ⁽³⁾
I/O	P123	P142	M18	M17	568 ⁽³⁾

XCS40 and XCS40XL Device Pinouts

XCS40/XL Pad Name	PQ208	PQ240	BG256	CS280 ^(2,5)	Bndry Scan
I/O	-	-	-	M18	571 ⁽³⁾
I/O	-	-	M19	M16	574 ⁽³⁾
I/O	P124	P144	M20	L19	577 ⁽³⁾
I/O	P125	P145	L19	L18	580 ⁽³⁾
I/O	P126	P146	L18	L17	583 ⁽³⁾
I/O	P127	P147	L20	L16	586 ⁽³⁾
I/O (D4 ⁽²⁾)	P128	P148	K20	K19	589 ⁽³⁾
I/O	P129	P149	K19	K18	592 ⁽³⁾
VCC	P130	P150	VCC ⁽⁴⁾	VCC ⁽⁴⁾	-
GND	P131	P151	GND ⁽⁴⁾	GND ⁽⁴⁾	-
I/O (D3 ⁽²⁾)	P132	P152	K18	K16	595 ⁽³⁾
I/O	P133	P153	K17	K15	598 ⁽³⁾
I/O	P134	P154	J20	J19	601 ⁽³⁾
I/O	P135	P155	J19	J18	604 ⁽³⁾
I/O	P136	P156	J18	J17	607 ⁽³⁾
I/O	P137	P157	J17	J16	610 ⁽³⁾
I/O	-	-	H20	H19	613 ⁽³⁾
I/O	-	-	-	H18	616 ⁽³⁾
I/O (D2 ⁽²⁾)	P138	P159	H19	H17	619 ⁽³⁾
I/O	P139	P160	H18	H16	622 ⁽³⁾
VCC	P140	P161	VCC ⁽⁴⁾	VCC ⁽⁴⁾	-
I/O	P141	P162	G19	G18	625 ⁽³⁾
I/O	P142	P163	F20	G17	628 ⁽³⁾
I/O	-	P164	G18	G16	631 ⁽³⁾
I/O	-	P165	F19	F19	634 ⁽³⁾
GND	P143	P166	GND ⁽⁴⁾	GND ⁽⁴⁾	-
I/O	-	P167	F18	F18	637 ⁽³⁾
I/O	P144	P168	E19	F17	640 ⁽³⁾
I/O	P145	P169	D20	F16	643 ⁽³⁾
I/O	P146	P170	E18	F15	646 ⁽³⁾
I/O	P147	P171	D19	E19	649 ⁽³⁾
I/O	P148	P172	C20	E17	652 ⁽³⁾
I/O (D1 ⁽²⁾)	P149	P173	E17	E16	655 ⁽³⁾
I/O	P150	P174	D18	D19	658 ⁽³⁾
I/O	-	-	-	D18	661 ⁽³⁾
I/O	-	-	-	D17	664 ⁽³⁾
I/O	P151	P175	C19	C19	667 ⁽³⁾
I/O	P152	P176	B20	B19	670 ⁽³⁾
I/O (D0 ⁽²⁾ , DIN)	P153	P177	C18	C18	673 ⁽³⁾
I/O, SGCK4 ⁽¹⁾ , GCK6 ⁽²⁾ (DOUT)	P154	P178	B19	B18	676 ⁽³⁾
CCLK	P155	P179	A20	A19	-
VCC	P156	P180	VCC ⁽⁴⁾	VCC ⁽⁴⁾	-

XCS40 and XCS40XL Device Pinouts

XCS40/XL Pad Name	PQ208	PQ240	BG256	CS280 ^(2,5)	Bndry Scan
O, TDO	P157	P181	A19	B17	0
GND	P158	P182	GND ⁽⁴⁾	GND ⁽⁴⁾	-
I/O	P159	P183	B18	A18	2
I/O, PGCK4 ⁽¹⁾ , GCK7 ⁽²⁾	P160	P184	B17	A17	5
I/O	P161	P185	C17	D16	8
I/O	P162	P186	D16	C16	11
I/O (CS1 ⁽²⁾)	P163	P187	A18	B16	14
I/O	P164	P188	A17	A16	17
I/O	-	-	-	E15	20
I/O	-	-	-	C15	23
I/O	P165	P189	C16	D15	26
I/O	-	P190	B16	A15	29
I/O	P166	P191	A16	E14	32
I/O	P167	P192	C15	C14	35
I/O	P168	P193	B15	B14	38
I/O	P169	P194	A15	D14	41
GND	P170	P196	GND ⁽⁴⁾	GND ⁽⁴⁾	-
I/O	P171	P197	B14	A14	44
I/O	P172	P198	A14	C13	47
I/O	-	P199	C13	B13	50
I/O	-	P200	B13	A13	53
VCC	P173	P201	VCC ⁽⁴⁾	VCC ⁽⁴⁾	-
I/O	-	-	A13	A12	56
I/O	-	-	D12	C12	59
I/O	P174	P202	C12	B12	62
I/O	P175	P203	B12	D12	65
I/O	P176	P205	A12	A11	68
I/O	P177	P206	B11	B11	71
I/O	P178	P207	C11	C11	74
I/O	P179	P208	A11	D11	77
I/O	P180	P209	A10	A10	80
I/O	P181	P210	B10	B10	83
GND	P182	P211	GND ⁽⁴⁾	GND ⁽⁴⁾	-

2/8/00

Notes:

1. 5V Spartan family only
2. 3V Spartan-XL family only
3. The "PWRDWN" on the XCS40XL is not part of the Boundary Scan chain. For the XCS40XL, subtract 1 from all Boundary Scan numbers from GCK3 on (343 and higher).
4. Pads labeled GND⁽⁴⁾ or VCC⁽⁴⁾ are internally bonded to Ground or VCC planes within the package.
5. CS280 package discontinued by [PDN2004-01](#)

Additional XCS40/XL Package Pins

PQ240

GND Pins					
P22	P37	P83	P98	P143	P158
P204	P219	-	-	-	-
Not Connected Pins					
P195	-	-	-	-	-

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BG256

VCC Pins					
C14	D6	D7	D11	D14	D15
E20	F1	F4	F17	G4	G17
K4	L17	P4	P17	P19	R2
R4	R17	U6	U7	U10	U14
U15	V7	W20	-	-	-
GND Pins					
A1	B7	D4	D8	D13	D17
G20	H4	H17	N3	N4	N17
U4	U8	U13	U17	W14	-

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CS280

VCC Pins					
A1	A7	B5	B15	C10	C17
D13	E3	E18	G1	G19	K2
K17	M4	N16	R3	R18	T7
U3	U10	U17	V5	V15	W13
GND Pins					
E5	E7	E8	E9	E11	E12
E13	G5	G15	H5	H15	J5
J15	L5	L15	M5	M15	N5
N15	R7	R8	R9	R11	R12
R13	-	-	-	-	-

5/19/99